

TVS Diode Array For ESD and Latch-Up Protection

The TT0515NLX is designed to protect sensitive electronics from damage or latch -up due to ESD and other voltage induced transient events. They are designed for use in applications where board space is at a premium. Each device will protect up to five lines. They are unidirectional devices and may be used on lines where the signal polarities are above ground. TVS Diode Array For ESD and Latch-Up Protection

Features

- Protects five I/O lines
- Low capacitance
- Working voltages : 5V
- Low leakage current
- Response Time is < 1 ns
- Low operating and clamping voltages
- Solid-state silicon avalanche technology
- Device Meets MSL 1 Requirements
- ROHS compliant

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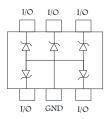
SOT-23-6L



- Cellular Handsets and Accessories
- Cordless Phones
- Personal Digital Assistants (PDA's)
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- MP3 Players

Protection solution to meet

- IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)



Ordering Information

Device	Qty per Reel	Reel Size
TT0515NLX	3000	7 Inch



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Maximum ratings (Tamb=25°C Unless Otherwise Specified)						
Parameter	Symbol	Value	Unit			
Peak Pulse Power (tp=8/20µs waveform)	Рррр	50	Watts			
Peak Pulse Current(tp=8/20µs waveform)	Ірр	2.5	А			
ESD Rating per IEC61000-4-2: Contact		8	KV			
Air		15				
Lead Soldering Temperature	TL	260 (10 sec.)	°C			
Operating Temperature Range	TJ	-55 ~ 150	°C			
Storage Temperature Range	Tstg	-55 ~ 150	°C			

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not

normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

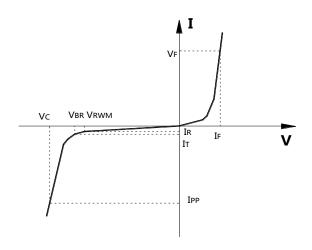
*Other voltages may be available upon request.

1. Non-repetitive current pulse, per Figure 1.

Electrica	Electrical characteristics (Tamb=25°C Unless Otherwise Specified)							
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units		
Vrwm	Reverse Working Voltage				5.0	V		
VBR	Reverse Breakdown Voltage	$I_{\rm T}=1{\rm mA},$	6.0			V		
Ir	Reverse Leakage Current	$V_{RWM} = 5V,$			100	nA		
VF	Diode Forward Voltage	$I_F = 15 mA$		0.85	1.2	V		
Vc	Clamping Voltage	$I_{PP} = 1A$, tp =8/20µs,			10	V		
		$I_{PP} = 2.5A$, tp =8/20µs,			13	V		
I _{PP}	Peak Pulse Current	tp =8/20µs			2.5	А		
C _J	Junction Capacitance	$V_{R} = 0V, f = 1MHz,$		60		pF		

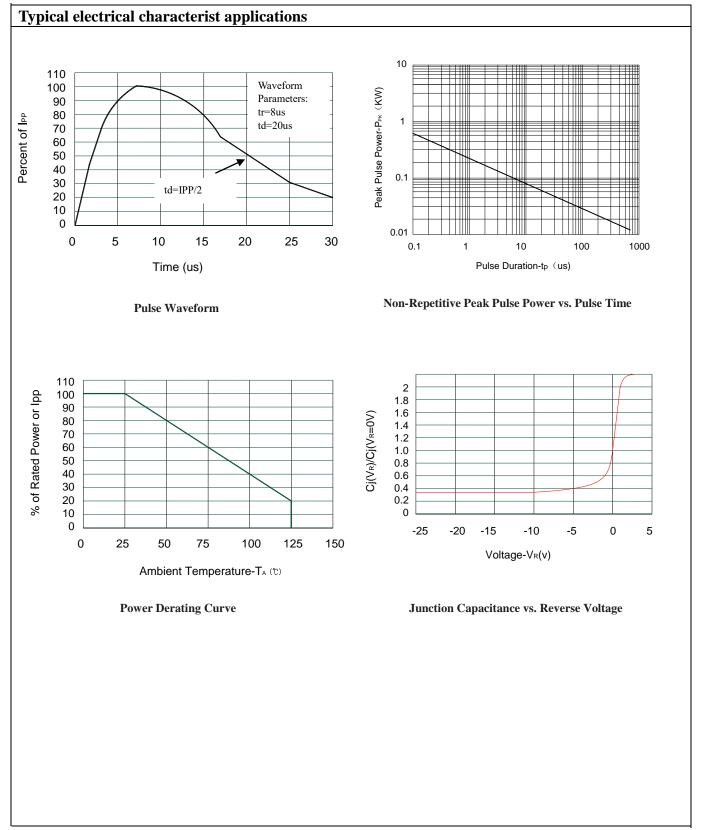
Junction capacitance is measured in VR=0V,F=1MHz

Symbol	Parameter		
Vrwm	Working Peak Reverse Voltage		
VBR	Breakdown Voltage @ IT		
V _C	Clamping Voltage @ IPP		
I _T	Test Current		
Irm	Leakage current at VRWM		
Ipp	Peak pulse current		
Co	Off-state Capacitance		
C _J	Junction Capacitance		



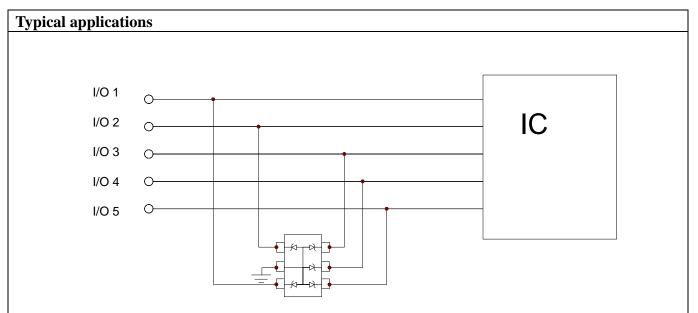


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Device Connection for Protection of Five Data Lines

The TT0515NLX is designed to protect up to four unidirectional data lines. The device is connected as follows:

Unidirectional protection of five I/O lines is achieved by connecting pins 1, 3, 4,5and 6 to the data lines. Pin 2 is connected to ground. The ground connection should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.



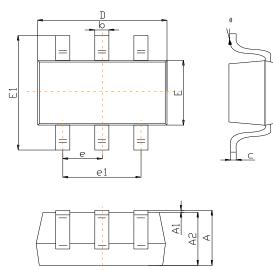
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Package Information

Mechanical Data

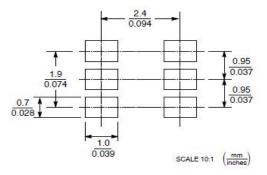
SOT23-6L

- Case: SOT23-6L
- Case Material: Molded Plastic. UL Flammability

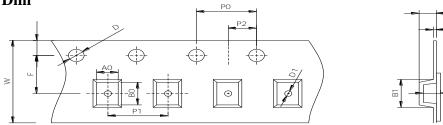


DIM	Millimeters		Inches		
DIM	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
Е	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0,950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0	8°	0	8°	

Recommended Pad outline



SOT23-6L Reel Dim



Package	Chip Size	Pocket Size B0×A0×K0(mm)	Tape Width	Reel Diameter	Quantity Per Reel	PO	P1
SOT23-6L	3.00×1.60×1.20	3.20×1.80×1.40	8mm	178mm(7")	3000	4mm 4mm	
D0	D1	Е	F	K	Т	W	
1.5mm	1.0mm	1.75mm	3.5mm	1.25mm	0.2mm	8mm	

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